2SA1215

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC2921)

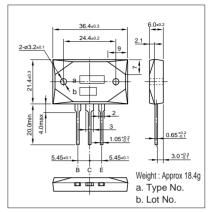
Application: Audio and General Purpose

Absolute maximum ratings (Ta=25°C) Symbol 2SA1215 Unit Vсво -160 VCEO -160 ٧ VEBO -5 ٧ lc -15 Α Ιв -4 Α Pc W 150(Tc=25°C) Τį 150 °C Tstg -55 to +150 °C

Electrical Cl	naracteristics	(Ta=25°C)		
Symbol	Conditions 2SA1215		Unit	
Ісво	VcB=-160V	-100max	μΑ	
І ЕВО	VEB=-5V	-100max	μΑ	
V(BR)CEO	Ic=-25mA	-160min	V	
hfe	Vce=-4V, Ic=-5A	50min*		
Vce(sat)	Ic=-5A, IB=-0.5A	-2.0max	V	
fr	VCE=-12V, IE=2A	50typ	MHz	
Сов	VcB=-10V, f=1MHz	400typ	pF	

*hfe Rank \overline{O}(50 to 100), P(70 to 140), Y(90 to 180)

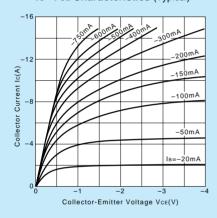
External Dimensions MT-200



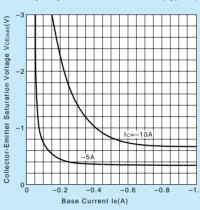
Typical Switching Characteristics (Common Emitter)

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Vcc (V)	R _L (Ω)	Ic (A)	V _{B2} (V)	I _{B1} (mA)	I _{B2} (mA)	ton (µs)	tstg (µs)	tf (µs)
-60	12	-5	5	-500	500	0.25typ	0.85typ	0.2typ

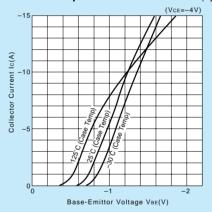
Ic-VcE Characteristics (Typical)



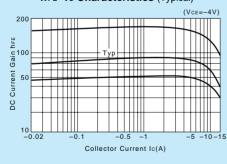




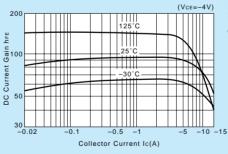
Ic-VBE Temperature Characteristics (Typical)



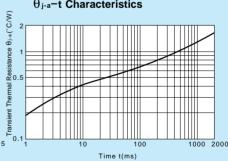
hfe-Ic Characteristics (Typical)



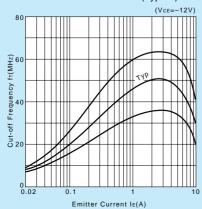
hfe-Ic Temperature Characteristics (Typical)



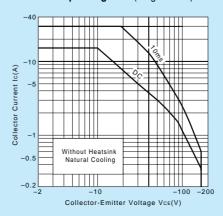
θ_{j-a}-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

